

FZT689BTC Datasheet

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DiGi Electronics Part Number	FZT689BTC-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	FZT689BTC
Description	TRANS NPN 20V 3A SOT223-3
Detailed Description	Bipolar (BJT) Transistor NPN 20 V 3 A 150MHz 2 W S urface Mount SOT-223-3



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Purchase and inquiry

Manufacturer Product Number:

FZT689BTC

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

20 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

2 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

FZT689

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

450mV @ 20mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

400 @ 2A, 2V

Frequency - Transition:

150MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Affected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99



FZT689B

20V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- $BV_{CEO} > 20V$
- $BV_{CBO} > 20V$
- $I_C = 3.0A$ High Continuous Current
- $h_{FE} > 400$ @ 2A and Low Saturation Voltage
- $V_{CE(sat)} < 450mV$ at 3A
- Complementary PNP Type: DIODES™ FZT789B
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

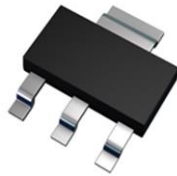
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 Ⓔ
- Weight: 0.112 grams (Approximate)

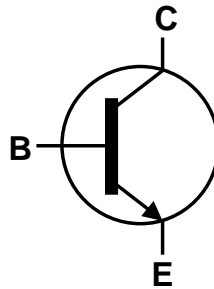
Applications

- Darlington replacements
- Flash gun converters and battery powered circuits

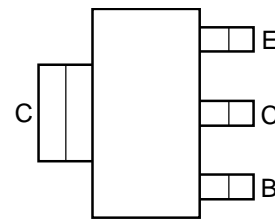
SOT223 (Type DN)



Top View



Device Symbol

Top View
Pin-Out

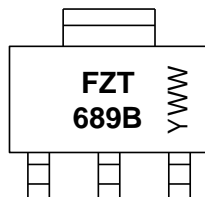
Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
FZT689BTA	SOT223 (Type DN)	FZT689B	7	12	1,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT223 (Type DN)



FZT689B = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 3 = 2023)
 WW or $\bar{W}W$ = Week Code (01 to 53)



FZT689B

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	20	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EB0}	7	V
Continuous Collector Current	I _C	3	A
Peak Pulse Current	I _{CM}	8	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5)	3
		(Note 6)	2
		(Note 7)	1.6
		(Note 8)	1.2
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5)	41.7
		(Note 6)	62.5
		(Note 7)	78.1
		(Note 8)	104
Thermal Resistance Junction to Lead	R _{θJL}	12.9	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

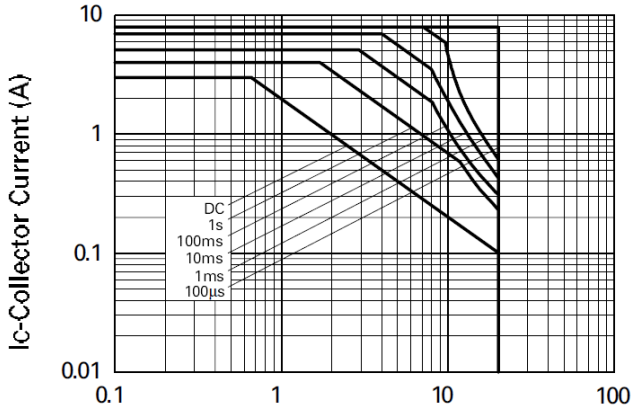
ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge — Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge — Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 - Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 - Same as Note 5, except the device is mounted on minimum recommended pad layout.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



VCE - Collector Emitter Voltage (V)
Figure 1. Safe Operating Area

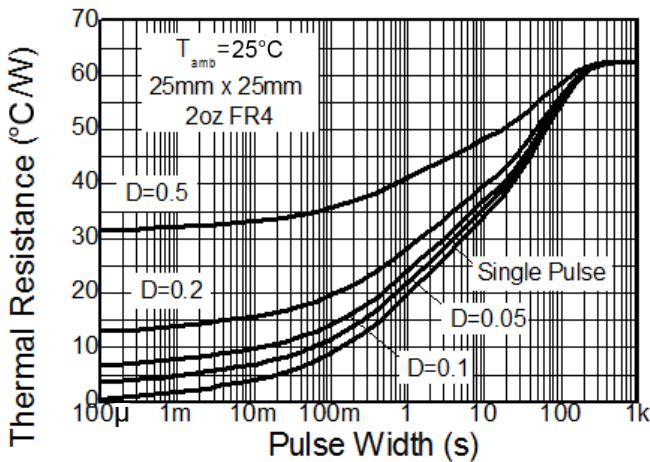


Figure 2. Transient Thermal Impedance

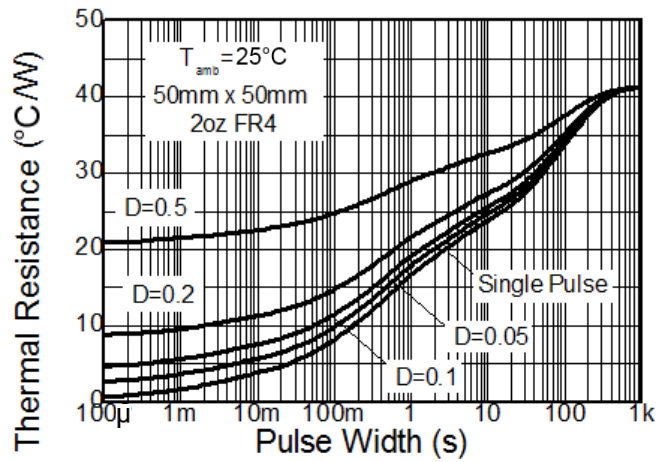


Figure 3. Transient Thermal Impedance

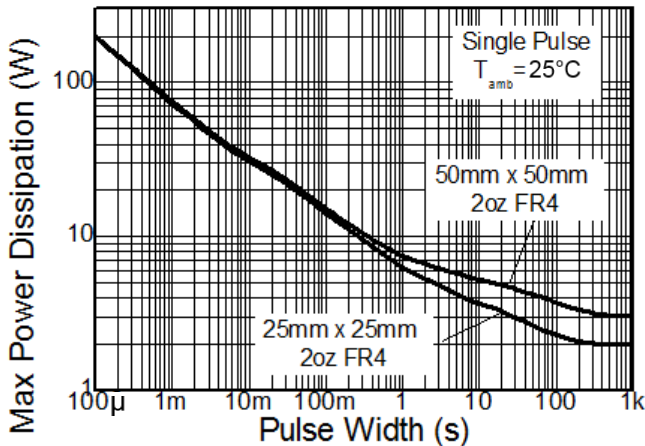


Figure 4. Pulse Power Dissipation

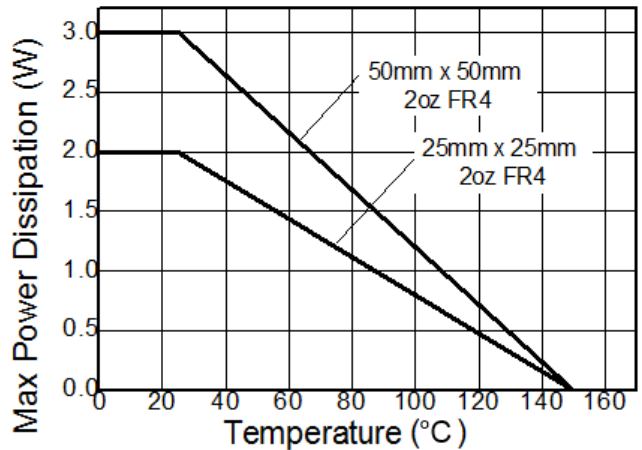


Figure 5. Derating Curve



FZT689B

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	20	—	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	20	—	—	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	—	—	V	$I_E = 100\mu\text{A}$
Collector-Base Cut-Off Current	I_{CBO}	—	—	50	nA	$V_{CB} = 16\text{V}$
Emitter Cut-Off Current	I_{EBO}	—	—	50	nA	$V_{EB} = 6\text{V}$
DC Current Gain (Note 11)	h_{FE}	500	—	—	—	$I_C = 0.1\text{A}, V_{CE} = 2\text{V}$
		400	—	—		$I_C = 2\text{A}, V_{CE} = 2\text{V}$
		150	—	—		$I_C = 6\text{A}, V_{CE} = 2\text{V}$
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	—	—	100	mV	$I_C = 0.1\text{A}, I_B = 0.5\text{mA}$
		—	—	500		$I_C = 2\text{A}, I_B = 10\text{mA}$
		—	—	450		$I_C = 3\text{A}, I_B = 20\text{mA}$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	—	—	0.9	V	$I_C = 1\text{A}, I_B = 10\text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	—	—	0.9	V	$I_C = 1\text{A}, V_{CE} = 2\text{V}$
Input Capacitance	C_{ibo}	—	200	—	pF	$V_{EB} = 0.5\text{V}, f = 1\text{MHz}$
Output Capacitance	C_{obo}	—	16	—	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Current Gain-Bandwidth Product	f_T	150	—	—	MHz	$V_{CE} = 5\text{V}, I_C = 50\text{mA}, f = 50\text{MHz}$
Turn-On Time	t_{on}	—	30	—	ns	$V_{CC} = 10\text{V}, I_C = 500\text{mA},$
Turn-Off Time	t_{off}	—	800	—	ns	$I_{B1} = -I_{B2} = 50\text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

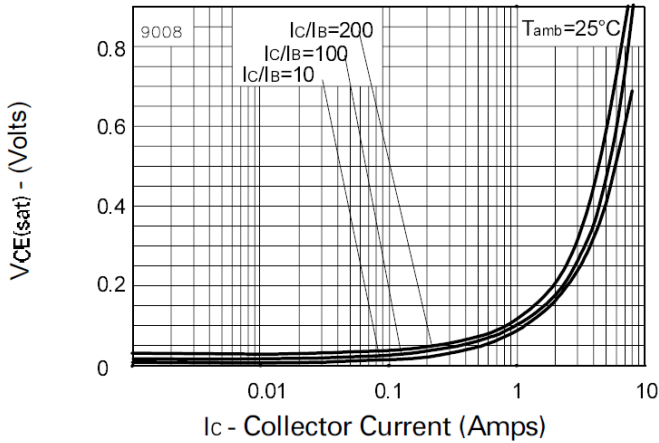


Figure 6. $V_{CE(sat)}$ vs. I_C

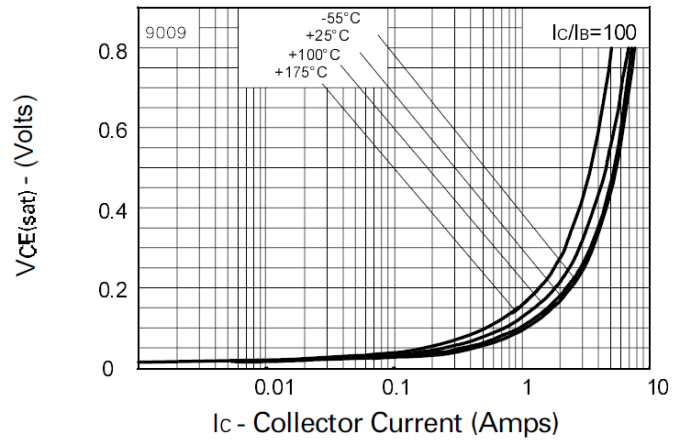


Figure 7. $V_{CE(sat)}$ vs. I_C

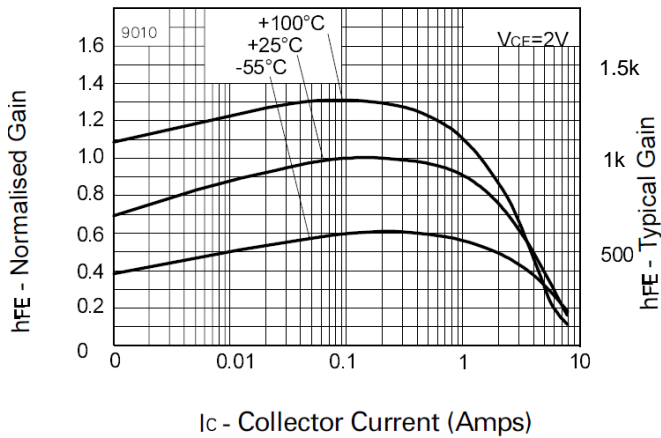


Figure 8. h_{FE} vs. I_C

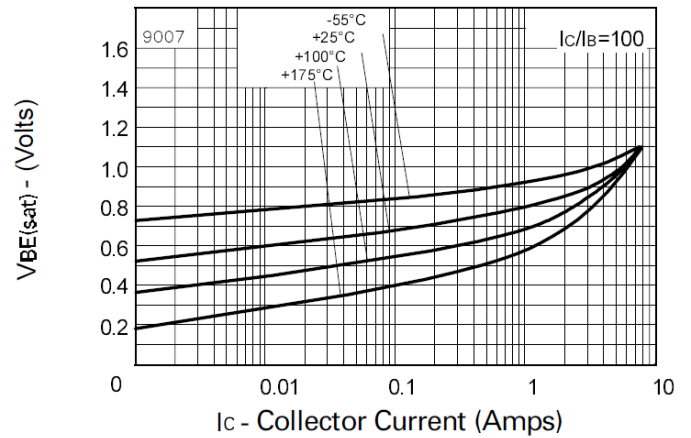


Figure 9. $V_{BE(sat)}$ vs. I_C

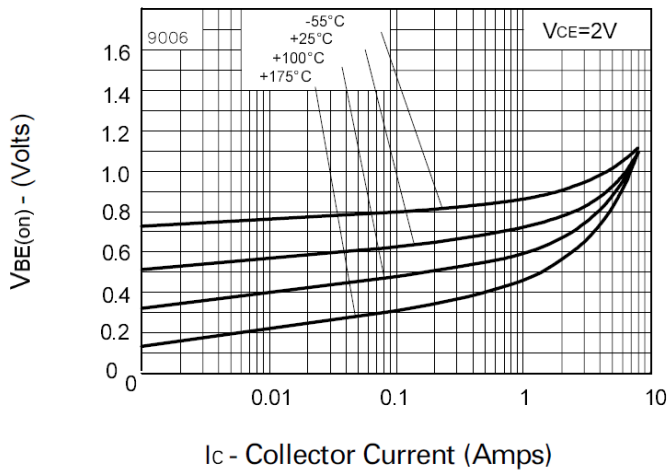
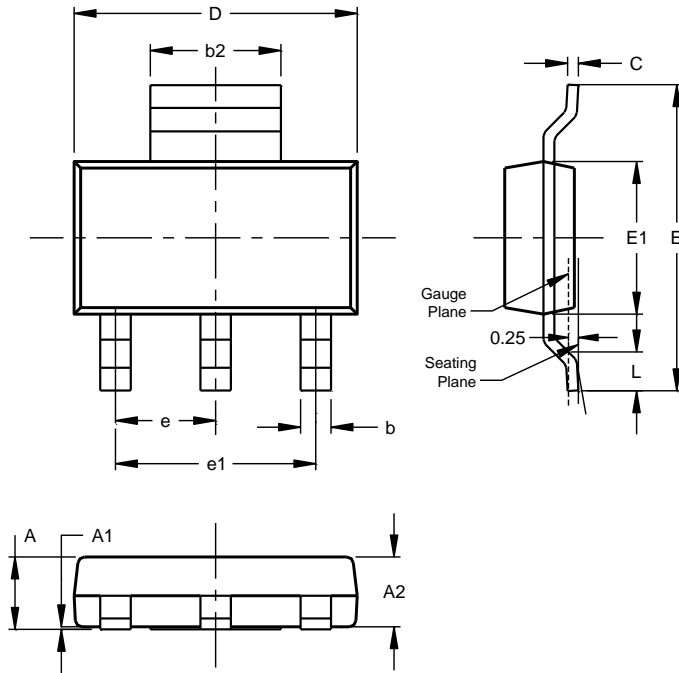


Figure 10. $V_{BE(on)}$ vs. I_C

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

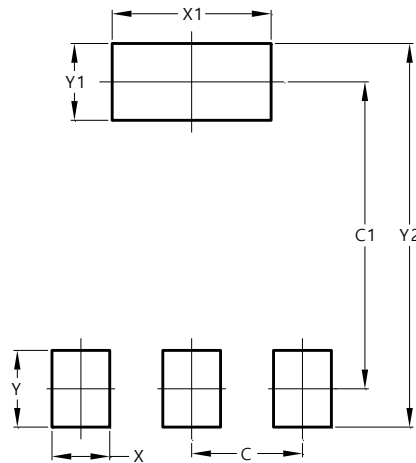


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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